Technical Data	escale Semiconductor chnical Data		Doo	Document Number: MHW7205CL Rev. 5, 3/200			
CATV Amplifier M	odule						
<ul> <li>Features</li> <li>Specified for 77- and 110-Channel</li> <li>Lower DC Current Requirements</li> </ul>				MHW	7205C	LN	
<ul> <li>Silicon Bipolar Transistor Technolog</li> <li>Unconditionally Stable Under All Lo</li> <li>Applications</li> <li>CATV Systems Operating in the 40</li> <li>Output Stage Amplifier in Optical No</li> </ul>	ellent DC Current Stability over Temperature con Bipolar Transistor Technology conditionally Stable Under All Load Conditions			750 MHz 20 dB GAIN 110-CHANNEL CATV AMPLIFIER MODULE			
<ul> <li>Distribution Amplifiers for CATV Sys</li> <li>Driver Amplifier in Linear General P</li> <li>Amplifier Requiring Lower Power D Output Performance</li> <li>Description</li> <li>24 Vdc Supply, 40 to 750 MHz, CAT Module</li> <li>Replaced MHW7205CL. There are this part replacement.</li> <li>RoHS Compliant</li> </ul>	Purpose Applications issipation While Maintai IV Forward Power Dout	bler Amplifier					
				CASE 71	4Y-04, STY	LE 1	
Table 1. Maximum Ratings				CASE 71	4Y-04, STY		
Ra	ting		Symbol	Va	lue	Unit	
Rate RF Voltage Input (Single Tone)	ting		V <sub>in</sub>	Va	<b>llue</b>	<b>Unit</b> dBmV	
Ra RF Voltage Input (Single Tone) DC Supply Voltage	ting		V <sub>in</sub> V <sub>CC</sub>	Va + +	1 <b>ue</b> 70 28	Unit dBmV Vdc	
Rat RF Voltage Input (Single Tone) DC Supply Voltage Operating Case Temperature Range	ting		V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub>	Va + +	<b>llue</b>	Unit dBmV Vdc °C	
Ra RF Voltage Input (Single Tone) DC Supply Voltage Operating Case Temperature Range Storage Temperature Range		75.0 content of	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub>	Va ++ -20 to -40 to	1 <b>ue</b> 70 28	Unit dBmV Vdc	
Rat RF Voltage Input (Single Tone) DC Supply Voltage Operating Case Temperature Range			V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub>	Va + -20 to -40 to noted)	lue 70 28 0 +100	Unit dBmV Vdc °C	
Rate Rate Rate Rate Rate Rate Rate Rate		75 Ω system unle Symbol BW	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise	Va ++ -20 to -40 to	Iue       70       28       p +100       p +100	Unit dBmV Vdc °C °C Unit	
Ra RF Voltage Input (Single Tone) DC Supply Voltage Operating Case Temperature Range Storage Temperature Range Table 2. Electrical Characteristics (V Characteristic		Symbol	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise Min	Va + -20 to -40 to noted)	Iue     70       28     28       p +100     20       p +100     Max	Unit dBmV Vdc °C °C	
Rate         RF Voltage Input (Single Tone)         DC Supply Voltage         Operating Case Temperature Range         Storage Temperature Range         Table 2. Electrical Characteristics (V         Characteristic         Frequency Range	/ <sub>CC</sub> = 24 Vdc, T <sub>C</sub> = +30°C, 50 MHz	Symbol BW	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise Min 40 19	Va + -20 to -40 to noted) Typ  19.5	Mue       70       28       0 +100       0 +100       Max       750       20	Unit dBmV Vdc °C °C Unit MHz	
Ra         RF Voltage Input (Single Tone)         DC Supply Voltage         Operating Case Temperature Range         Storage Temperature Range         Table 2. Electrical Characteristics (V         Characteristic         Frequency Range         Power Gain	V <sub>CC</sub> = 24 Vdc, T <sub>C</sub> = +30°C, 50 MHz 750 MHz 40 - 750 MHz	Symbol BW G <sub>p</sub>	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise Min 40 19 19.7	Va           +           -20 td           -40 td           noted)           Typ           -19.5           20	Mue       70       28       p +100       p +100       p +100       Max       750       20       21.2	Unit dBmV Vdc °C °C Unit MHz dB	
Rate         Rate         Rate         Reperting Complete Tone)         DC Supply Voltage         Operating Case Temperature Range         Storage Temperature Range         Table 2. Electrical Characteristics (V         Characteristics (V         Characteristics         Frequency Range         Power Gain         Slope	/ <sub>CC</sub> = 24 Vdc, T <sub>C</sub> = +30°C, 50 MHz 750 MHz 40 - 750 MHz lley)	Symbol BW G <sub>p</sub> S	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise Min 40 19 19.7 0.2	Va       +       -20 to       -40 to       noted)       Typ          19.5       20       0.5	Mue       70       28       0 +100       0 +100       0 +100       0 -100       Max       750       20       21.2       1.7	Unit dBmV Vdc °C °C Unit MHz dB dB	
Rai         Rai         Rai         R Voltage Input (Single Tone)         DC Supply Voltage         Operating Case Temperature Range         Storage Temperature Range         Table 2. Electrical Characteristics (V         Characteristics (V         Frequency Range         Power Gain         Slope         Gain Flatness (40 - 750 MHz, Peak to Va	/ <sub>CC</sub> = 24 Vdc, T <sub>C</sub> = +30°C, 50 MHz 750 MHz 40 - 750 MHz lley) ms) @ 40 MHz	Symbol BW G <sub>p</sub> S G <sub>F</sub>	V <sub>in</sub> V <sub>CC</sub> T <sub>C</sub> T <sub>stg</sub> ess otherwise Min 40 19 19.7 0.2 —	Va       +       -20 to       -40 to       noted)       Typ          19.5       20       0.5	Mue       70       28       p +100       p +100       p +100       Max       750       20       21.2       1.7       0.8	Unit dBmV Vdc °C °C Unit MHz dB dB dB	

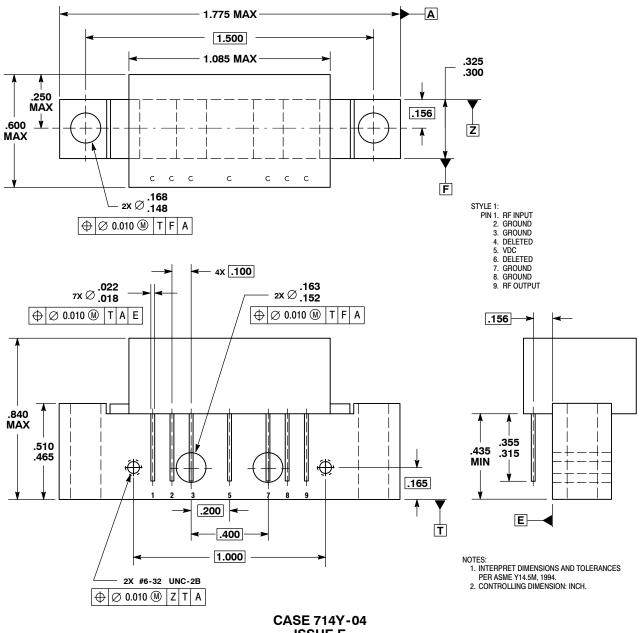
Characteristic	;	Symbol	Min	Тур	Max	Unit
Composite Triple Beat						dBc
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	110-Channel FLAT	CTB <sub>110</sub>	_	-63	-61	
	77-Channel FLAT	CTB <sub>77</sub>	—	-70	-68	
Noise Figure	50 MHz	NF	_	5.0	6.2	dB
	550 MHz		—	5.8	—	
	750 MHz		-	6.2	7.5	
DC Current ( $V_{DC}$ = 24 V, $T_{C}$ = -20 to +1	00°C)	I <sub>DC</sub>	345	365	385	mA

# Table 2. Electrical Characteristics (V<sub>CC</sub> = 24 Vdc, T<sub>C</sub> = +30°C, 75 $\Omega$ system unless otherwise noted) (continued)

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# MHW7205CLN

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